

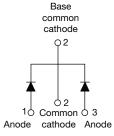
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# High Performance Schottky Rectifier, 2 x 8 A

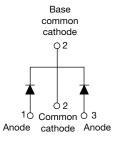
# VS-16CTQ...SPbF











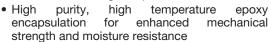
D<sup>2</sup>PAK

TO-262

PRODUCT SUMMARY	
Package	TO-263AB (D <sup>2</sup> PAK), TO-262AA
I <sub>F(AV)</sub>	2 x 8 A
V <sub>R</sub>	60 V, 80 V, 100 V
V <sub>F</sub> at I <sub>F</sub>	0.58 V
I <sub>RM</sub>	7 mA at 125 °C
T <sub>J</sub> max.	175 °C
Diode variation	Common cathode
E <sub>AS</sub>	7.5 mJ

### **FEATURES**

- 175 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop





**RoHS** COMPLIANT **HALOGEN** 

FREE

- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- · Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION**

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I <sub>F(AV)</sub>	Rectangular waveform	16	Α				
V <sub>RRM</sub>		60 to 100	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	850	Α				
V <sub>F</sub>	8 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.58	V				
TJ	Range	-55 to +175	°C				

VOLTAGE RATINGS							
PARAMETER SYMBOL   VS-16CTQ060SPbF   VS-16CTQ080SPbF   VS-16CTQ080SPbF   VS-16CTQ100SPbF   VS-16CTQ080-1PbF   VS-16CTQ100-1PbF   VS-16CTQ100-1PbF							
Maximum DC reverse voltage	V <sub>R</sub>	60	80	100	\/		
Maximum working peak reverse voltage	$V_{RWM}$	00	00	100	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS	
Maximum average per leg				8		
forward current See fig. 5  per device	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 148 °C, rectangular waveform		16	А	
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load	850		
non-repetitive surge current per leg See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse condition and with rated V <sub>RRM</sub> applied		275	A	
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 0.50 A, L = 60 mH		7.50	mJ	
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero Frequency limited by $T_J$ maxim	•	0.50	А	



# VS-16CTQ...SPbF, VS-16CTQ...-1PbF Series

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		8 A	T <sub>.1</sub> = 25 °C	0.72		
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	16 A	1j=25 C	0.88	V	
See fig. 1	V <sub>FM</sub> (1)	8 A	T 105 °C	0.58		
		16 A	T <sub>J</sub> = 125 °C	0.69		
Maximum reverse leakage current per leg	ı (1)	T <sub>J</sub> = 25 °C	V Data IV	0.55	A	
See fig. 2	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	7.0	mA	
Threshold voltage	V <sub>F(TO)</sub>	T T mayimum		0.415	V	
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		11.07	mΩ	
Maximum junction capacitance per leg	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		500	pF	
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 m	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs	

### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C
Maximum thermal resistance, junction to case per leg		В		3.25	
Maximum thermal resistance, junction to case per package		- R <sub>thJC</sub>	DC operation	1.63	°C/W
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	
Approximate weight				2	g
Approximate weight				0.07	OZ.
Manustina taurus	minimum			6 (5)	kgf · cm
Mounting torque r	maximum			12 (10)	(lbf · in)
Marking davise			Case style D <sup>2</sup> PAK	16CT	QS
Marking device			Case style TO-262	16CT	Q1

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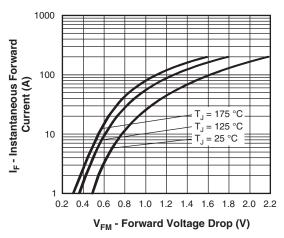


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

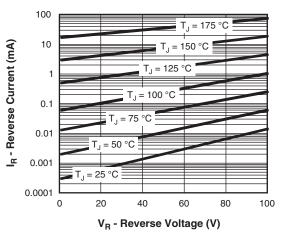


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

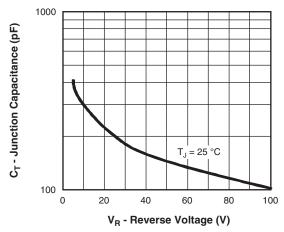


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

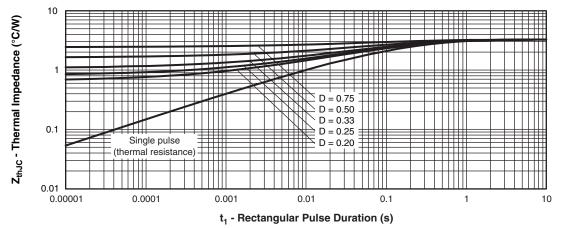


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

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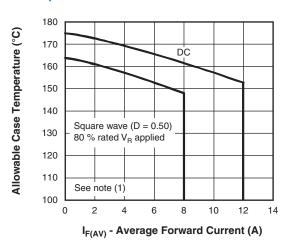


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

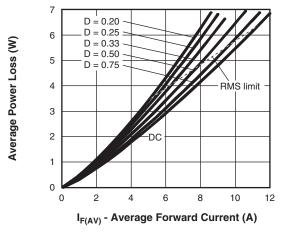


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

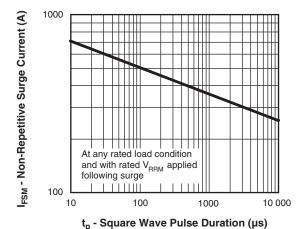


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

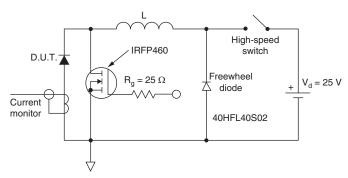


Fig. 8 - Unclamped Inductive Test Circuit

## Note

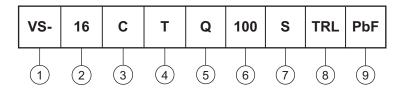
[1] Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$ ;  $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = Inverse$  power loss  $= V_{R1} \times I_{R}$  (1 - D);  $I_{R}$  at  $V_{R1} = 80$  % rated  $V_{R}$  applied

# VS-16CTQ...SPbF, VS-16CTQ...-1PbF Series

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### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product suffix

2 - Current rating (16 A)

3 - Circuit configuration: C = Common cathode

**4** - T = TO-220

5 - Schottky "Q" series

7 - • S = D<sup>2</sup>PAK

• -1 = TO-262

8 - • None = Tube (50 pieces)

• TRL = Tape and reel (left oriented - for D<sup>2</sup>PAK only)

• TRR = Tape and reel (right oriented - for D<sup>2</sup>PAK only)

9 - PbF = Lead (Pb)-free

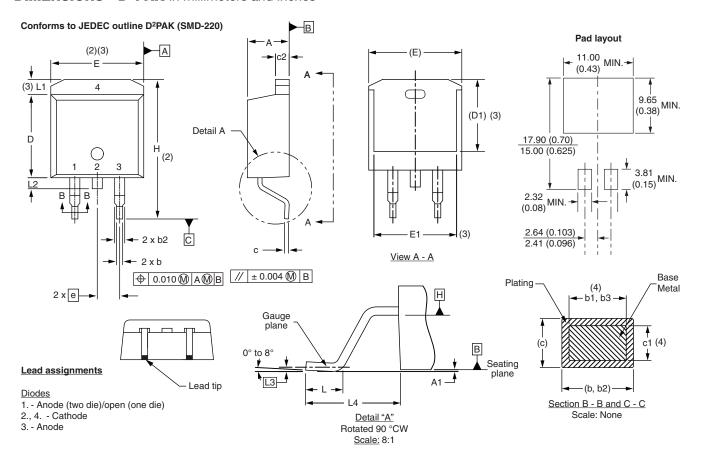
LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95014							
Part marking information	www.vishay.com/doc?95008						
Packaging information	www.vishay.com/doc?95032						
SPICE model	www.vishay.com/doc?95279						



# Vishay Semiconductors

# **D<sup>2</sup>PAK, TO-262**

# **DIMENSIONS - D<sup>2</sup>PAK** in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	NOTES	
STIMBUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIN	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100 BSC			
Н	14.61	15.88	0.575	0.625		
L	1.78	2.79	0.070	0.110		
L1	-	1.65	-	0.066	3	
L2	1.27	1.78	0.050	0.070		
L3	0.25 BSC		0.010	BSC		
L4	4.78	5.28	0.188	0.208		

### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$  Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

(7) Outline conforms to JEDEC outline TO-263AB

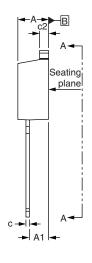
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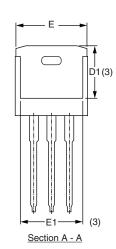
D<sup>2</sup>PAK, TO-262



### **DIMENSIONS - TO-262** in millimeters and inches

# Modified JEDEC outline TO-262 (Datum A) (2) (3) (3) 1 L2 B B B L (2) 3 x b2 3 x b2 3 x b2





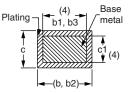
⊕ 0.010 M AM B

Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIM	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	2.54 BSC		) BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

### Notes

- $^{(1)}$  Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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